TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS160C

August 1997 - Revised October 2003

Features

- Common Clock and Asynchronous Reset on Four D-Type Flip-Flops
- Positive Edge Pulse Triggering
- Complementary Outputs
- Buffered Inputs
- Fanout (Over Temperature Range)
 - Standard Outputs..... 10 LSTTL Loads
- Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: NIL = 30%, NIH = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, II \leq 1 μA at V_OL, V_OH

Description

The 'HC175 and 'HCT175 are high speed Quad D-type Flip-Flops with individual D-inputs and Q, \overline{Q} complementary outputs. The devices are fabricated using silicon gate CMOS technology. They have the low power consumption

CD54HC175, CD74HC175, CD54HCT175, CD74HCT175

High-Speed CMOS Logic Quad D-Type Flip-Flop with Reset

advantage of standard CMOS ICs and the ability to drive 10 LSTTL devices.

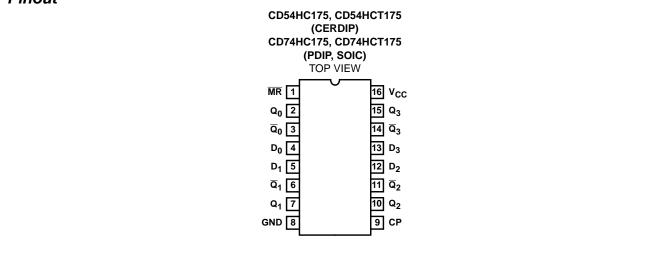
Information at the D input is transferred to the Q, \overline{Q} outputs on the positive going edge of the clock pulse. All four Flip-Flops are controlled by a common clock (CP) and a common reset (\overline{MR}). Resetting is accomplished by a low voltage level independent of the clock. All four Q outputs are reset to a logic 0 and all four \overline{Q} outputs to a logic 1.

Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC175F3A	-55 to 125	16 Ld CERDIP
CD54HCT175F3A	-55 to 125	16 Ld CERDIP
CD74HC175E	-55 to 125	16 Ld PDIP
CD74HC175M	-55 to 125	16 Ld SOIC
CD74HC175MT	-55 to 125	16 Ld SOIC
CD74HC175M96	-55 to 125	16 Ld SOIC
CD74HCT175E	-55 to 125	16 Ld PDIP
CD74HCT175M	-55 to 125	16 Ld SOIC
CD74HCT175MT	-55 to 125	16 Ld SOIC
CD74HCT175M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

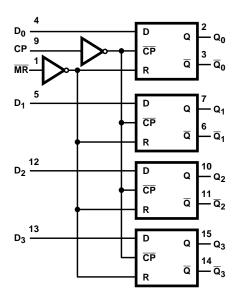
Pinout



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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Functional Diagram

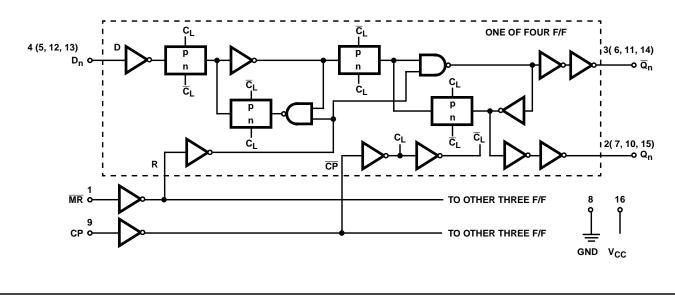


TRUTH TABLE

	INPUTS					
RESET (MR)	CLOCK CP	DATA D _n	Q _n	Q _n		
L	Х	Х	L	н		
Н	\uparrow	н	Н	L		
Н	\uparrow	L	L	н		
Н	L	Х	Q ₀	\overline{Q}_0		

H = High Voltage Level, L = Low Voltage Level, X = Don't Care, \uparrow = Transition from Low to High Level, Q_0 = Level Before the Indicated Steady-State Input Conditions Were Established.

Logic Diagram



Absolute Maximum Ratings

DC Supply Voltage, V _{CC}
DC Input Diode Current, I _{IK}
For $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, IOK
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC or} I _{GND} ±50mA
Operating Conditions

Temperature Range (T _A)
Supply Voltage Range, V _{CC}
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (^o C/W)
E (PDIP) Package	
M (SOIC) Package	. 73
Maximum Junction Temperature	150 ⁰ C
Maximum Storage Temperature Range	-65 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			ST ITIONS			25 ⁰ C		-40 ⁰ C T	0 +85 ⁰ C	-55 ⁰ C T	O 125 ⁰ C				
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS			
HC TYPES															
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V			
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V			
				6	4.2	-	-	4.2	-	4.2	-	V			
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V			
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V			
				6	-	-	1.8	-	1.8	-	1.8	V			
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V			
Voltage CMOS Loads		VIL	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V			
			1			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-4	4.5	3.98	-	-	3.84	-	3.7	-	V			
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	V			
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V			
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V			
			0.02	6	-	-	0.1	-	0.1	-	0.1	V			
Low Level Output	1		4	4.5	-	-	0.26	-	0.33	-	0.4	V			
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V			
Input Leakage Current	lı	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA			
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μA			

CD54HC175, CD74HC175, CD54HCT175, CD74HCT175

DC Electrical Specifications	(Continued)
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			ST ITIONS			25 ⁰ C			O +85 ⁰ C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	VIL	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	Ιį	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	ICC	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTES:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
MR	1
СР	0.60
D	0.15

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. 360 μA max at 25 $^{o}C.$

Prerequisite For Switching Specifications

TES		TEST	Vcc	25°C			-40°C TO 85°C		-55°C TO 125°C		
SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS	
	-										
t _w	-	2	80	-	-	100	-	120	-	ns	
		4.5	16	-	-	20	-	24	-	ns	
		6	14	-	-	17	-	20	-	ns	
t _w	-	2	80	-	-	100	-	120	-	ns	
		4.5	16	-	-	20	-	24	-	ns	
		6	14	-	-	17	-	20	-	ns	
	t _w	t _w -	SYMBOL CONDITIONS (V) t _w - 2 4.5 6 t _w - 2 t _w - 2 t _w - 2 4.5 6 4.5	SYMBOL CONDITIONS (V) MIN t _w - 2 80 4.5 16 6 14 t _w - 2 80 t _w - 2 80 4.5 16 6 14 t _w - 2 80 4.5 16 16 16	SYMBOL TEST CONDITIONS V _{CC} (V) MIN TYP t _w - 2 80 - 4.5 16 - - t _w - 2 80 - t _w - 2 80 - 4.5 16 - - - t _w - 2 80 - 4.5 16 - - -	SYMBOL TEST CONDITIONS V _{CC} (V) MIN TYP MAX t _w - 2 80 - - 4.5 16 - - - t _w - 2 80 - - 4.5 16 - - - - t _w - 2 80 - - t _w - 2 80 - - 4.5 16 - - - -	SYMBOL TEST CONDITIONS V _{CC} (V) MIN TYP MAX MIN t_w - 2 80 - - 100 4.5 16 - - 20 6 14 - 20 t_w - 2 80 - - 100 t_w - 2 80 - - 100 t_w - 2 80 - - 100 t_w - 2 16 - - 20	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	

CD54HC175, CD74HC175, CD54HCT175, CD74HCT175

		TEST	v _{cc}		25 ⁰ C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
Setup Time, Data to Clock	t _{SU}	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Hold Time, Data to Clock	t _H	-	2	5	-	-	5	-	5	-	ns
			4.5	5	-	-	5	-	5	-	ns
			6	5	-	-	5	-	5	-	ns
Removal Time, MR to Clock	t _{REM}	-	2	5	-	-	5	-	5	-	ns
			4.5	5	-	-	5	-	5	-	ns
			6	5	-	-	5	-	5	-	ns
Clock Frequency	f _{MAX}	-	2	6	-	-	5	-	4	-	MHz
			4.5	30	-	-	25	-	20	-	MHz
			6	35	-	-	29	-	23	-	MHz
HCT TYPES	•										
Clock Pulse Width	tw	-	4.5	20	-	-	25	-	30	-	ns
MR Pulse Width	t _w	-	4.5	20	-	-	25	-	30	-	ns
Setup Time Data to Clock	t _{SU}	-	4.5	20	-	-	25	-	30	-	ns
Hold Time Data to Clock	t _H	-	4.5	5	-	-	5	-	5	-	ns
Removal Time MR to Clock	t _{REM}	-	4.5	5	-	-	5	-	5	-	ns
Clock Frequency	f _{MAX}	-	4.5	25	-	-	20	-	16	-	MHz

Prerequisite For Switching Specifications (Continued)

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25 ⁰ C		-40°C TO 85°C	-55 ⁰ C TO 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	МАХ	МАХ	MAX	
HC TYPES								
Propagation Delay, Clock to Q or \overline{Q}	t _{PLH} , t _{PHL}	$C_L = 50 pF$	2	-	175	220	265	ns
Q or Q			4.5	-	35	44	53	ns
			6	-	30	37	45	ns
		C _L = 15pF	5	14	-	-	-	ns
Propagation Delay, $\overline{\text{MR}}$ to Q or $\overline{\text{Q}}$	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	175	220	265	ns
			4.5	-	35	44	53	ns
			6	-	30	37	45	ns
		C _L = 15pF	5	14	-	-	-	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	2	-	75	95	110	ns
			4.5	-	15	19	22	ns
			6	-	13	16	19	ns
Input Capacitance	C _{IN}	-	-	-	10	10	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	65	-	-	-	pF

CD54HC175, CD74HC175, CD54HCT175, CD74HCT175

		TEST		25 ⁰ C		-40 [°] C TO 85 [°] C	-55 ⁰ C TO 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	ТҮР	МАХ	MAX	MAX	
HCT TYPES	-	-				••		
Propagation Delay, Clock to Q or \overline{Q}	t _{PLH} , t _{PHL}	$C_L = 50 pF$	4.5	-	33	41	50	ns
		C _L = 15pF	5	13	-	-	-	ns
Propagation Delay, \overline{MR} to Q or \overline{Q}	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	35	44	53	ns
		C _L = 15pF	5	17	-	-	-	ns
Output Transition Times	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	15	19	22	ns
Input Capacitance	C _{IN}	-	-	-	10	10	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	67	-	-	-	pF

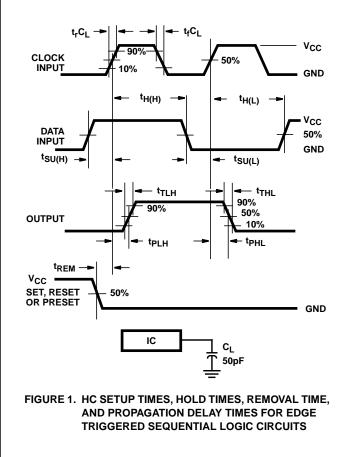
Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

NOTES:

3. C_{PD} is used to determine the dynamic power consumption, per flip-flop.

4. $P_D = V_{CC}^2 f_i + \sum (C_L V_{CC}^2 + f_O)$ where $f_i = Input$ Frequency, $f_O = Input$ Frequency, $C_L = Output$ Load Capacitance, $V_{CC} = Supply$ Voltage.





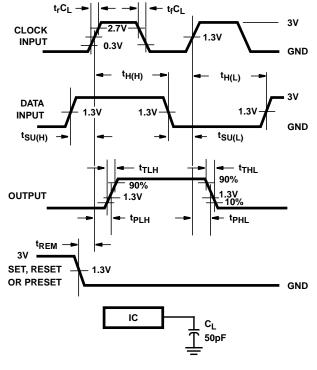


FIGURE 2. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8970101EA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8970101EA CD54HCT175F3A	Samples
CD54HC175F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	8408901EA CD54HC175F3A	Samples
CD54HCT175F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8970101EA CD54HCT175F3A	Samples
CD74HC175E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC175E	Samples
CD74HC175EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC175E	Samples
CD74HC175M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HC175MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC175M	Samples
CD74HCT175E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT175E	Samples
CD74HCT175EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT175E	Samples
CD74HCT175M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples



25-Sep-2013

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
CD74HCT175M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples
CD74HCT175M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples
CD74HCT175M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples
CD74HCT175ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples
CD74HCT175MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples
CD74HCT175MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples
CD74HCT175MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples
CD74HCT175MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT175M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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PACKAGE OPTION ADDENDUM

25-Sep-2013

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54HC175, CD54HCT175, CD74HC175, CD74HC175;

- Catalog: CD74HC175, CD74HCT175
- Military: CD54HC175, CD54HCT175

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

TEXAS INSTRUMENTS www.ti.com

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions a	re nominal												
Devic	e l	0	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC1	′5M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT1	75M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC175M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT175M96	SOIC	D	16	2500	333.2	345.9	28.6

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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